

Available online at www.sciencedirect.com





Journal of Magnetism and Magnetic Materials 297 (2006) 118-140

www.elsevier.com/locate/jmmm

## Accurate measurement of the in-plane magnetic anisotropy energy function $E_a(\theta)$ in ultrathin films by magneto-optics

D. Berling<sup>\*</sup>, S. Zabrocki, R. Stephan, G. Garreau, J.L. Bubendorff, A. Mehdaoui, D. Bolmont, P. Wetzel, C. Pirri, G. Gewinner

Laboratoire de Physique et de Spectroscopie Electronique—CNRS UMR 7014, Université de Haute Alsace, Faculté des Sciences et Techniques, 4 rue des frères Lumière, F-68093 Mulhouse Cedex, France

> Received 6 January 2005; received in revised form 25 February 2005 Available online 25 March 2005

## Abstract

We present a sensitive and precise determination of an arbitrary thin film magnetic anisotropy energy  $E_a$  (or  $E_a/M_S$ ) if the saturation magnetization  $M_{\rm S}$  is not known) versus in-plane polar angle  $\theta$  by means of initial inverse susceptibility and torque measurements under constant transverse bias field  $H_{\rm B}$ . In this method coined **TBIIST** two magnetic fields  $H_{\rm L}$  and  $H_{\rm B}$  are applied in the plane of the film along directions defined by  $\theta$  and  $\theta - (\pi/2)$ , respectively, and  $m_{\rm L}$  the magnetization component in units of  $M_{\rm S}$  is measured versus  $H_{\rm L}$  around  $m_{\rm L} = 0$ . This readily provides two quantities  $\chi^{-1} = (\partial H_{\rm L}/\partial m_{\rm L})(m_{\rm L} = 0)$  the initial inverse susceptibility and  $\Delta H = H_{\rm L}(m_{\rm L} = 0)$  the field offset or torque at  $m_{\rm L} = 0$ , shown to be respectively related to the second  $(1/M_{\rm S})(\partial^2 E_{\rm a}/\partial\theta^2)(\theta - (\pi/2))$  and first  $(1/M_{\rm S})(\partial E_{\rm a}/\partial\theta)(\theta - \pi/2)$ derivatives of  $E_a$ . This, in turn, yields two determinations of  $E_a(\theta)$  from  $\chi^{-1}(\theta)$  and  $\Delta H(\theta)$ , respectively. Fourier analysis then easily resolves various contributions of different symmetries to the magnetic anisotropy. The magnetization  $m_{\rm L}(H_{\rm L})$  is measured with a conventional magneto-optical Kerr experiment in longitudinal geometry with respect to  $H_{\rm L}$ and higher-order (nonlinear in  $m_{\rm L}$ ) contributions as well as polar or other contributions to the Kerr signal are carefully determined and corrected in order to obtain the desirable accuracy or even simply meaningful results. Typical acquisition times including all corrections are about a few minutes per angle  $\theta$ . The power of the method is demonstrated on typical examples of epitaxial Fe layers on Si(001) and Si(111) substrates. For instance, it is shown that extremely small contributions up to the 12th order in-spin to the cubic magnetocrystalline anisotropy of iron are readily detected.

© 2005 Elsevier B.V. All rights reserved.

PACS: 07.10P; 07.55.J; 78.20.L; 75.50.Bd; 75.70.Ak; 75.30.Gw

Keywords: Magneto-optics; Torque measurement; Magnetic susceptibility; Magnetic anisotropy; Thin films; Iron

<sup>\*</sup>Corresponding author. Tel.: +33 03 89 33 60 06; fax: +33 03 89 33 60 83. *E-mail address:* dominique.berling@uha.fr (D. Berling).

<sup>0304-8853/\$-</sup> see front matter © 2005 Elsevier B.V. All rights reserved. doi:10.1016/j.jmmm.2005.02.069

## 1. Introduction

In magnetic materials the energy required to magnetize a crystal depends on the direction of the applied field. Ferromagnetic materials exhibit intrinsic easy and hard directions of magnetization reflecting the magnetic anisotropy. The two main sources of magnetic anisotropy are the dipolar and the spin-orbit interactions. The first one is a longrange effect that results in a contribution to the anisotropy which depends on the shape of the specimen, and is largely responsible for the inplane remanent magnetization observed in thin films. The second one, the so-called magnetocrystalline anisotropy, due to the spin-orbit interaction reflects the symmetry of the crystal. In thin films and low-dimension systems, the symmetry breaking at surfaces and interfaces, the strain induced by substrate-film lattice mismatch or between adjacent layers, the growth on stepped substrates, the lattices distortion, the roughness and the interdiffusion at interface and/or film surface induced by the deposition conditions can drastically modify the magnetic anisotropy compared to that in the respective bulk material. In particular, due to the symmetry reduction new additional lower order components of the anisotropy may be generated. The actual observed anisotropy contributions can be phenomenologically described by effective magnetic anisotropy constants  $K_n$  taking into account the crystal structure symmetry, the symmetry breaking at surfaces and interfaces and the shape modifications.  $K_n$  associated to the *n*th order magnetic anisotropy contribution usually include a volume term  $K_n^{\text{Vol}}$  and an interface term  $K_n^{\text{Int}}$  [1–6]:

$$K_n = K_n^{\text{Vol}} + \frac{K_n^{\text{Int}}}{Nd},\tag{1}$$

where N and d are, respectively, the film thickness in atomic layers and the interlayer distance perpendicular to the film surface. The most general expression of the magnetic anisotropy free energy density of a single domain can be written as

$$E_{a} = K_{0} + \sum_{n} [K_{n} \times f_{n}(\alpha_{i})].$$
<sup>(2)</sup>

 $K_0$  accounts for an isotropic contribution. The functions  $f_n(\alpha_i)$  describe the dependence of the *n*th order anisotropy energy on the orientation of the magnetization expressed by the direction cosines  $(\alpha_i)$  relative to a given reference frame.

Magnetic anisotropy plays a key role in the physics of low-dimensional magnetic structures that reveal fascinating new properties with respect to those of the corresponding bulk materials: it affects the orientation and magnitude of the magnetization, the nature of the domain walls, the frequencies of the spin wave excitations, and hence the thermodynamic behavior of the film. The knowledge of the magnetic properties in ferromagnetic low-dimensional systems correlated to their changes in morphology due to controlled surfaces, interfaces and shape modifications is important from a point of view of basic research as well as with respect to the application in thin magnetic film and spintronics [7–9]. In particular, accurate determination of the different magnetic anisotropy contributions is needed to better understand the relationship between structural properties induced by the growth conditions and the magnetic ones.

The magnetic anisotropy is usually deduced either from dynamical or static response of the magnetic system [10]. The ferromagnetic resonance (FMR) [10-12], strain-modulated ferromagnetic resonance (SMFMR) [13] and the Brillouin light scattering (BLS) [3,14] probe the spin dynamics of a film in order to extract the anisotropy fields. These techniques give precise results but they are experimentally challenging and costly. Much of the experimental anisotropy constants have been obtained by static measurements using various magnetometry techniques such as alternating gradient force magnetometry (AGFM) [15], vibrating sample magnetometry (VMS) [16], superconducting quantum interference device magnetometry (SQUID) [17]. Magnetometry techniques are spatially averaging and accurate values can only be obtained from hysteresis loops for the simple case of uniaxial anisotropy. Moreover, absolute measurements are extremely difficult in the case of thin films where the diamagnetic signal from the substrate is comparable or larger than the magnetic film signal. Furthermore, torque magnetometry Download English Version:

## https://daneshyari.com/en/article/1803642

Download Persian Version:

https://daneshyari.com/article/1803642

Daneshyari.com